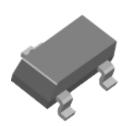
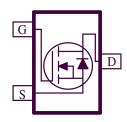
N-Channel 150V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(\Omega)$	$I_{D}(A)$		
150	$2.6 @ V_{GS} = 10 V$	0.6		
	$2.8 @ V_{GS} = 5.5V$	0.5		

- $\begin{tabular}{ll} \bullet & Low $r_{DS(on)}$ provides higher efficiency and extends battery life \\ \end{tabular}$
- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			150	V		
Gate-Source Voltage	V_{GS}	±20	v			
ntinuous Drain Current ^a $T_A=25^{\circ}C$ I_I		I_D	0.6	A		
Pulsed Drain Current ^b	I_{DM}	±10				
Continuous Source Current (Diode Conduction) ^a			1.1	A		
Power Dissipation ^a	$T_A=25^{\circ}C$	P_{D}	1.30	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Тур	Max			
Mariana Indiana da Ambinda	t <= 10 sec	R_{thJA}	93	110	0000	
Maximum Junction-to-Ambient ^a	Steady State		130	150	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM2392N

SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Danomatan	Symbol	T C 122	Limits			T I *4
Parameter		Test Conditions		Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V
Gate-Body Leakage	${ m I}_{ m GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			±25	μΑ
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
Zero Gate Voltage Drain Current	*DSS	$V_{DS} = 120 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			A
Drain-Source On-Resistance ^A		$V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$			2.6	Ω
Diani-Source On-Resistance	r _{DS(on)}	$V_{GS} = 5.5 \text{ V}, I_D = 0.5 \text{ A}$			2.8	
Forward Tranconductance ^A	g_{fs}	$V_{DS} = 10 \text{ V}, I_D = 0.5 \text{ A}$		11.3		S
Diode Forward Voltage	V_{SD}	$I_S = 0.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.75		V
Dynamic ^b						
Total Gate Charge	Q_{g}			7		
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 5.5 \text{ V}, I_{D} = 0.5 \text{ A}$		1.1		nC
Gate-Drain Charge	$Q_{ m gd}$			2		
Turn-On Delay Time	$t_{d(on)}$			8		
Rise Time	t _r	$V_{DD} = 10 \text{ V}, R_L = 15 \Omega, I_D = 1 \text{ A},$		24		
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 4.5 \text{ V}$		35		ns
Fall-Time	t_{f}			10		

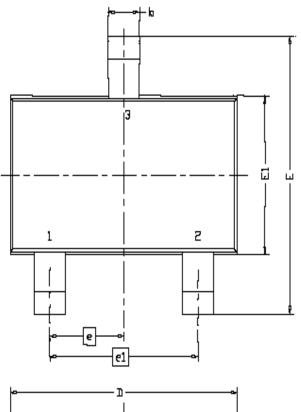
Notes

a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

b. Guaranteed by design, not subject to production testing.

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Package Information



DIM,	MILLIMETERS			
	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	0.925	
Ь	0.30	0.40	0.50	
С	0.10	0.15	0.25	
D	2.70	2.90	3.10	
Ε	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
L	0.30	0.40	0.60	
L1	0.60REF			
L2	0.25BSC			
R	0.10			
θ	Q*	4*	8,	
81	7*N□M			

